# DC - 700 MHz, 10 kOhm TRANSIMPEDANCE AMPLIFIER

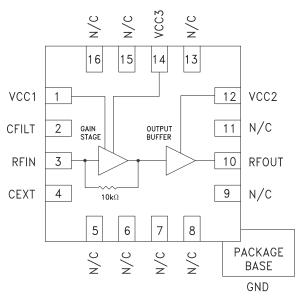


### Typical Applications

The HMC799LP3E is ideal for:

- Laser Sensor
- FDDI Receiver
- CATV FM Analog Receiver
- Wideband Gain Block
- Low Noise RF Applications

### **Functional Diagram**



#### **Features**

10 kOhm Transimpedance

Very Low Noise: 150nA Input RMS Noise

over 700 MHz Bandwidth 700 MHz Analog Bandwidth

Wide Dynamic Range: +65 dB

Low Power: 70mA from Single +5V Supply 16 Lead 3x3 mm SMT Package: 9mm²

### **General Description**

The HMC799LP3E is DC to 700 MHz Transimpedance amplifier designed for opto-electronic laser sensor applications, FDDI receivers and receiver systems employing optical to electrical conversion. This amplifier provides a single-ended output voltage that is proportional to an applied current at its input port. This current is typically provided by a photodiode. Operating from a single +5V supply, HMC799LP3E features very low input referred noise, and very large electrical input dynamic range exceeding 65 dB. 10 kOhm or 80 dB-Ohms transimpedance gain provides very good sensitivity at higher data rates. The output of HMC799LP3E is internally matched to 50 ohms. External matching is not necessary. The HMC799LP3E exhibits excellent gain and output power stability over temperature, while requiring a minimal number of external bias components.

# Electrical Specifications, $T_{A} = +25^{\circ}$ C, Vcc1 = Vcc2 = Vcc3 = +5V

Parameter	Conditions	Min.	Тур.	Max.	Units		
DC Specifications							
Power Supply Voltage		4.5	5	5.5	V		
Power Supply Current	Vcc = 5V	60	70	80	mA		
Input Impedance	@ 350 MHz		175		Ohm		
Input Bias Voltage			2.1		V		
AC Specifications	AC Specifications						
Transimpedance	@ 100 MHz, RL = 50 Ohm	7.5	10	12.5	k Ohms		
Transimpedance 3-dB Bandwidth		600	700		MHz		
Small Signal Gain	S21		42		dB		
	Cpd [1] <1pF, @ 200 MHz		4.6		pA / √Hz		
Input Deferred Current Naige Density	Cpd [1] = 1pF, @ 200 MHz		4.8		pA / √Hz		
Input Referred Current Noise Density	Cpd [1] = 2pF, @ 200 MHz		5.2		pA / √Hz		
	Cpd [1] = 3pF, @ 200 MHz		5.6		pA / √Hz		

[1] Cpd is the total parasitic capacitance value arises from addition of input photo diode. This value includes photo diode parasitic capacitance, PCB trace capacitance and package parasitic capacitance.



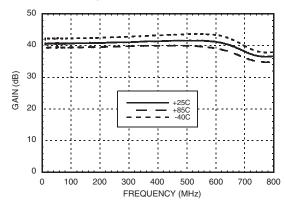


# DC - 700 MHz, 10 kOhm TRANSIMPEDANCE AMPLIFIER

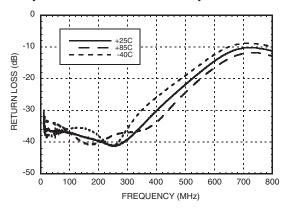
#### **Electrical Specifications** (Conditions)

Parameter	Conditions	Min.	Тур.	Max.	Units
	Cpd [1] <1pF, @ 700 MHz BW		149		nA RMS
Input Deferred DMC Current Naise	Cpd [1] = 1pF, @630 MHz BW		164		nA RMS
Input Referred RMS Current Noise	Cpd [1] = 2pF, @ 560 MHz BW		174		nA RMS
	Cpd [1] = 3pF, @ 420 MHz BW		132		nA RMS
Saturated Output Swing	Vin = 50mV p-p		1		Vp-p
Output Power 1-dB Compression	OP1dB @ 200 MHz		4		dBm
Output Third Order Intercept Point	OIP3 @ 200 MHz		13		dBm
Input Overdrive Current			20		mA
Output Return Loss	@ 500 MHz	16	20		dB

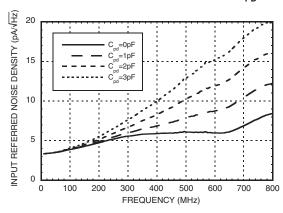
#### Gain vs. Temperature



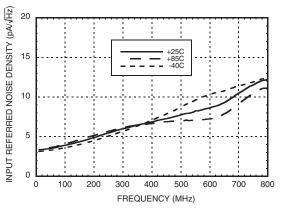
#### **Output Return Loss vs. Temperature**



# Input Referred Noise Density vs. Cpp [1]



# Input Referred Noise Density vs. Temperature [2]



[1] Cpd is the total parasitic capacitance value resulting from the addition of the input photo diode. This value includes photo diode parasitic capacitance, PCB trace capacitance and package parasitic capacitance.
[2] Cpd = 1 pF

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

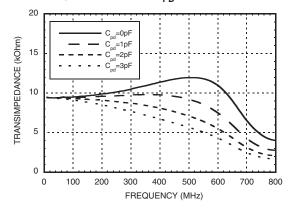
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



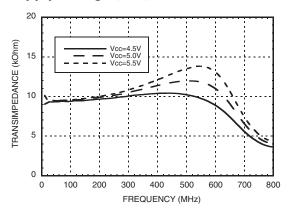


# DC - 700 MHz, 10 kOhm TRANSIMPEDANCE AMPLIFIER

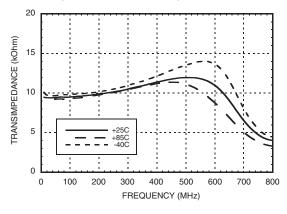
# Transimpedance vs. $C_{PD}^{[1]}$



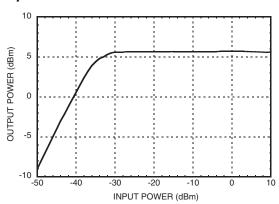
# Transimpedance vs. Supply Voltage (Vcc) [2]



### Transimpedance vs. Temperature [2]



# Output Power vs. Input Power @ 200 MHz [2]



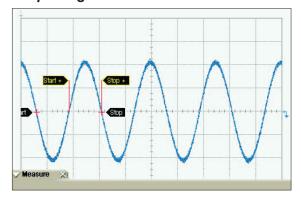
[1] Cpd is the total parasitic capacitance value resulting from the addition of the input photo diode. This value includes photo diode parasitic capacitance, PCB trace capacitance and package parasitic capacitance.
[2] Cpd = 1 pF





# DC - 700 MHz, 10 kOhm TRANSIMPEDANCE AMPLIFIER

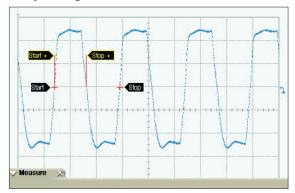
#### Output Signal [1]



	Measurements					
	Current	Mean	std dev	Min.	Max	Units
V amptd	198.84	200.50	3.6253	184.99	212.70	mV
Frequency	200.8	199.9	0.631	198.0	202.1	MHz
Duty Cycle	50.9	49.7	0.62	47.6	51.6	%

[1] Input signal current 25  $\mu$ Ap-p, frequency 200 MHz

### Output Signal [2]



		Measurements				
	Current	Mean	std dev	Min.	Max	Units
V amptd	959.62	960.47	3.703	953.11	972.63	mV
Frequency	200.1	200.0	0.117	199.5	200.4	MHz
Duty Cycle	49.1	49	0.08	48.7	49.2	%

[2] Input signal current 20 mAp-p, frequency 200 MHz



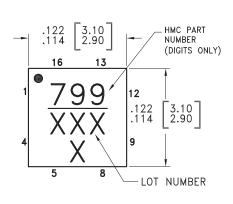


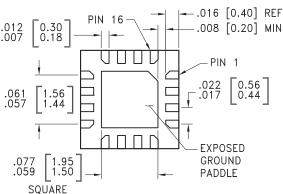
# DC - 700 MHz, 10 kOhm TRANSIMPEDANCE AMPLIFIER

## **Absolute Maximum Ratings**

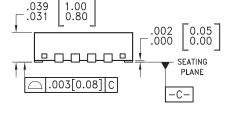
Power Supply Voltage (Vcc1, Vcc2, Vcc3)	-1V to 8V
Input Current	30 mAp-p
Junction Temperature	125 °C
Continuous Pdiss (T=85 °C) (derate 31.82 mW/ °C Above +85 °C	1.27W
Thermal Resistance (Junction to ground paddle)	31.43 °C/W
Storage Temperature	-65 to 125 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1C

## **Outline Drawing**





**BOTTOM VIEW** 



#### NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HMC APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

## Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [1]
HMC799LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>H799</u> XXXX

<sup>[1] 4-</sup>Digit lot number XXXX

<sup>[2]</sup> Max peak reflow temperature of 260 °C





# DC - 700 MHz, 10 kOhm TRANSIMPEDANCE AMPLIFIER

## **Pin Descriptions**

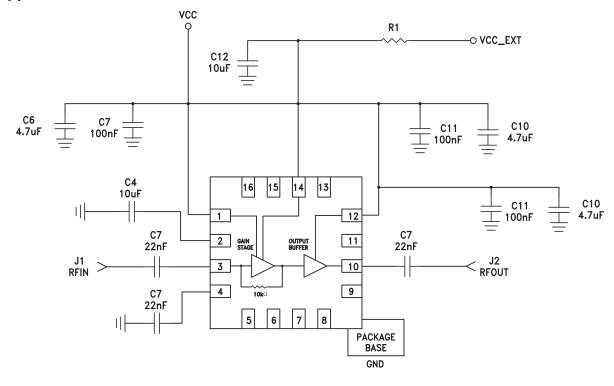
Pin Number	Function	Description	Interface Schematic
1, 12, 14	VCC1, VCC2, VCC3	Positive Supply	
2	CFILT	Overload current filter capacitance pin.	28k CFILT 22k
3	RFIN	RF Input	RFIN O
4	CEXT	Reference voltage filter capacitance pin.	CEXT O
5 - 9, 11, 13, 15, 16	N/C	Not connected.	
10	RFOUT	RF Output	500 RFOUT
Package Base	GND	Package base has exposed metal ground paddle which must be connected to ground.	GND =





# DC - 700 MHz, 10 kOhm TRANSIMPEDANCE AMPLIFIER

### **Application Circuit**



Note:

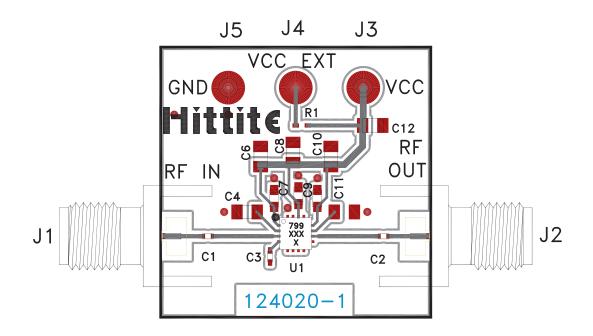
For power supply rejection ratio (PSRR) tests, install 0 Ohm for R1.





# DC - 700 MHz, 10 kOhm TRANSIMPEDANCE AMPLIFIER

#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 124022 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3, J5	DC Pin
C1 - C3	22 nF Capacitor, 0402 Pkg.
C4, C12	10 μF Capacitor, 0805 Pkg.
C6, C8, C10	4.7 μF Capacitor, 0805 Pkg.
C7, C9, C11	0.1 μF Capacitor, 0603 Pkg.
U1	HMC799LP3E Transimpedance Amplifier
PCB [2]	124020 Evaluation PCB

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

<sup>[2]</sup> Circuit Board Material: Arlon 25FR or Rogers 4350

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Development Tools category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below:

MAAM-011117 MAAP-015036-DIEEV2 EV1HMC1113LP5 EV1HMC6146BLC5A EV1HMC637ALP5 EVAL-ADG919EBZ ADL5363EVALZ LMV228SDEVAL SKYA21001-EVB SMP1331-085-EVB EV1HMC618ALP3 EVAL01-HMC1041LC4 MAAL-011111-000SMB
MAAM-009633-001SMB MASW-000936-001SMB 107712-HMC369LP3 107780-HMC322ALP4 SP000416870 EV1HMC470ALP3
EV1HMC520ALC4 EV1HMC244AG16 MAX2614EVKIT# 124694-HMC742ALP5 SC20ASATEA-8GB-STD MAX2837EVKIT+
MAX2612EVKIT# MAX2692EVKIT# EV1HMC629ALP4E SKY12343-364LF-EVB 108703-HMC452QS16G EV1HMC863ALC4 119197HMC658LP2 EV1HMC647ALP6 ADL5725-EVALZ 106815-HMC441LM1 EV1HMC1018ALP4 UXN14M9PE MAX2016EVKIT
EV1HMC939ALP4 MAX2410EVKIT MAX2204EVKIT+ EV1HMC8073LP3D SIMSA868-DKL SIMSA868C-DKL SKY65806-636EK1
SKY68020-11EK1 SKY67159-396EK1 SKY66181-11-EK1 SKY65804-696EK1 SKY13396-397LF-EVB